



Vincotech

flow PIM 0		1200 V / 5 A
Features		
	<ul style="list-style-type: none">• IGBT M7 with low V_{CEsat} and improved EMC behavior• Open emitter configuration• Compact and low inductive design• Built-in NTC	
Target applications		Schematic
	<ul style="list-style-type: none">• Industrial Drives	
Types		
	<ul style="list-style-type: none">• 10-F012PNA005M7-P848C29	

Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Rectifier Diode				
Peak Repetitive Reverse Voltage	V_{RRM}		1600	V
Continuous (direct) forward current	I_F		25	A
Surge (non-repetitive) forward current	I_{FSM}	50 Hz Single Half Sine Wave $t_p = 10 \text{ ms}$	200	A
Surge current capability	I^2t		200	A^2s
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	44	W
Maximum Junction Temperature	T_{jmax}		150	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current	I_C		5	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	10	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	41	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Inverter Diode

Peak repetitive reverse voltage	V_{RRM}		1200	V
Continuous (direct) forward current	I_F		5	A
Repetitive peak forward current	I_{FRM}	T_j limited by T_{jmax}	10	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	27	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2\text{ s}$	6000	V
		AC Voltage $t_p = 1\text{ min}$	2500	V
Creepage distance			min. 12,7	mm
Clearance		12 mm housing / 17 mm housing	9,29 / min. 12,7	mm
Comparative Tracking Index	CTI		> 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V]	V_{CE} [V]	I_c [A]	T_j [°C]	Min	Typ	Max		
			V_{GS} [V]	V_{DS} [V]	I_D [A]	I_F [A]					

Rectifier Diode

Static

Forward voltage	V_F				30	25 125		1,22 1,21	1,8	V
Reverse leakage current	I_r			1600		25 145			50 1100	µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,59		K/W
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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max			

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{GE} = V_{CE}$			0,0005	25	5,4	6	6,6	V
Collector-emitter saturation voltage	V_{CESat}		15		5	125 150		1,62 1,83 1,89	1,95	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			50	µA
Gate-emitter leakage current	I_{GES}		20	0		25			500	nA
Internal gate resistance	r_g						none			Ω
Input capacitance	C_{ies}		0	10	25	1100				pF
Output capacitance	C_{oes}									
Reverse transfer capacitance	C_{res}									
Gate charge	Q_g		15	600	5	25		40		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						2,30		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{goff} = 64 \Omega$ $R_{gon} = 64 \Omega$	± 15	600	5	25		153		
Rise time	t_r					125		150		
						150		147		
Turn-off delay time	$t_{d(off)}$					25		39		
						125		43		
Fall time	t_f					150		43		
Turn-on energy (per pulse)	E_{on}	$Q_{FWD} = 0,6 \mu\text{C}$ $Q_{FWD} = 0,8 \mu\text{C}$ $Q_{FWD} = 1 \mu\text{C}$				25		154		
						125		176		
Turn-off energy (per pulse)	E_{off}					150		181		
						25		89		
						125		115		
						150		111		
						25		0,480		
						125		0,601		
						150		0,643		
						25		0,333		
						125		0,437		
						150		0,473		



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Diode

Static

Forward voltage	V_F				5	25 125 150		1,57 1,65 1,65	2,1	V
Reverse leakage current	I_R			1200		25			20	µA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						3,50		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 83 \text{ A/}\mu\text{s}$ $di/dt = 111 \text{ A/}\mu\text{s}$ $di/dt = 92 \text{ A/}\mu\text{s}$	± 15	600	5	25 125 150		4 4 4		A
Reverse recovery time	t_{rr}					25 125 150		259 376 434		ns
Recovered charge	Q_r					25 125 150		0,551 0,773 0,985		µC
Reverse recovered energy	E_{rec}					25 125 150		0,186 0,273 0,378		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 125 150		46 24 25		A/µs

Thermistor

Rated resistance	R					25		22		kΩ
Deviation of R_{100}	$\Delta_{R/R}$	$R_{100} = 1484 \Omega$				100	-5		5	%
Power dissipation	P					25		5		mW
Power dissipation constant						25		1,5		mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %				25		3962		K
B-value	$B_{(25/100)}$	Tol. ±1 %				25		4000		K
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Rectifier Diode Characteristics

figure 1.
Typical forward characteristics

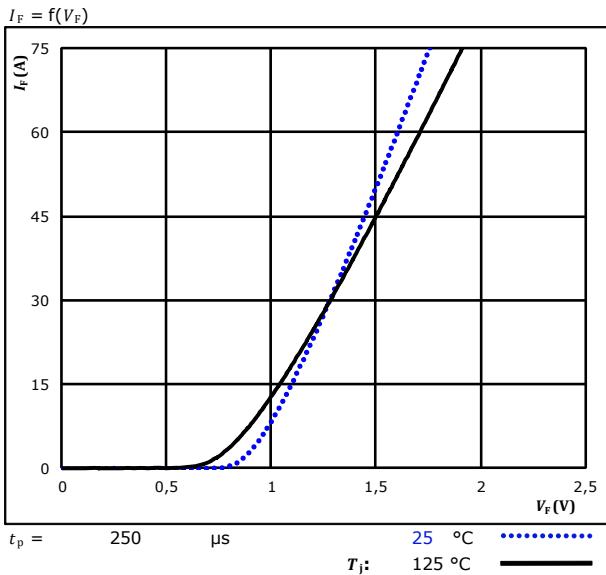
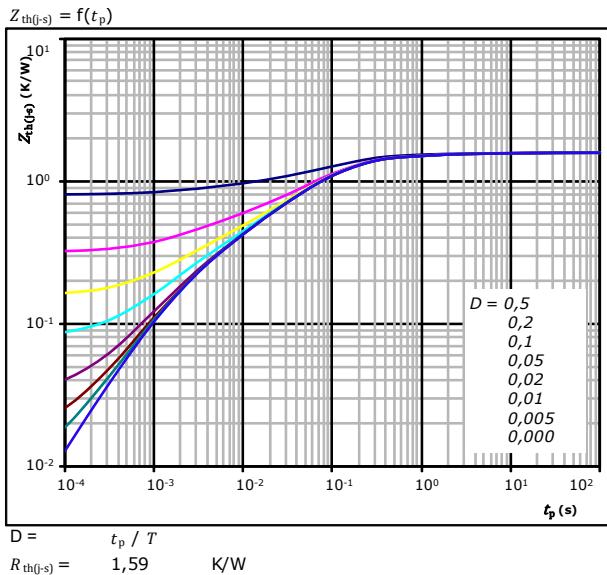


figure 2.
Transient thermal impedance as a function of pulse width



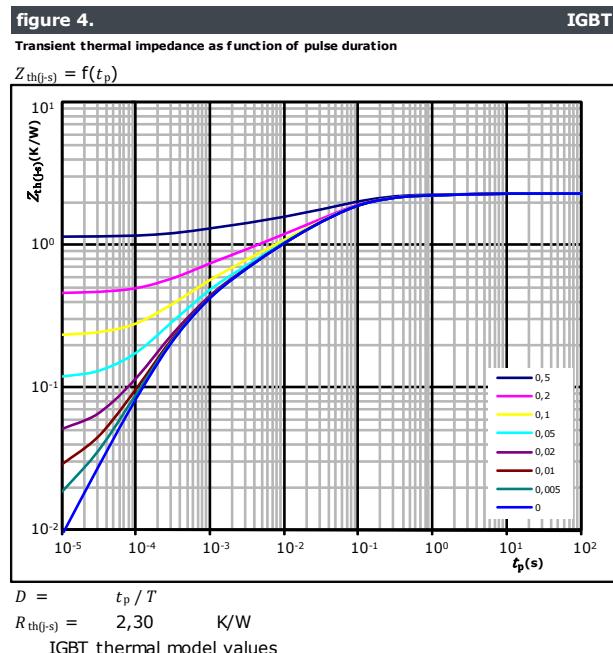
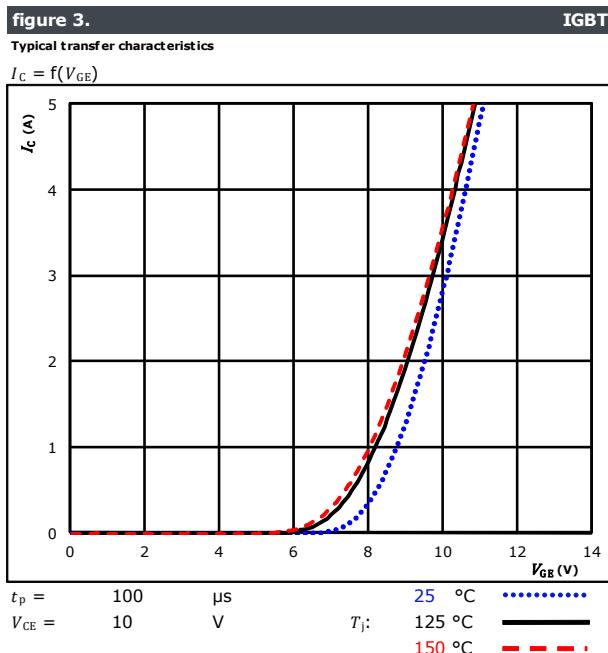
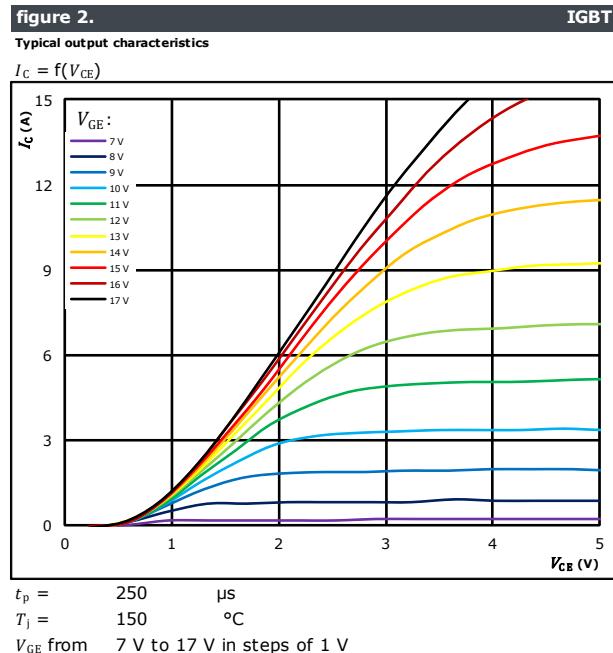
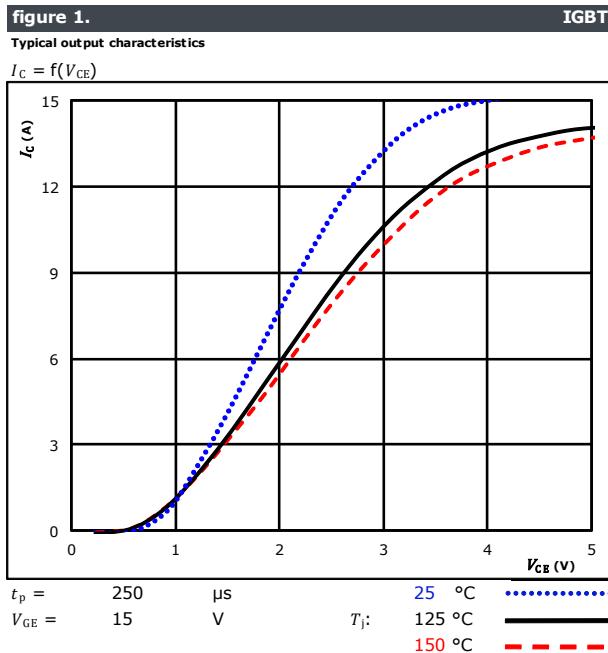
Diode thermal model values

R (K/W)	τ (s)
3,44E-02	9,66E+00
1,12E-01	1,22E+00
5,81E-01	1,45E-01
4,89E-01	5,05E-02
2,38E-01	9,26E-03
1,22E-01	1,79E-03
1,22E-01	1,79E-03



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Inverter Switch Characteristics

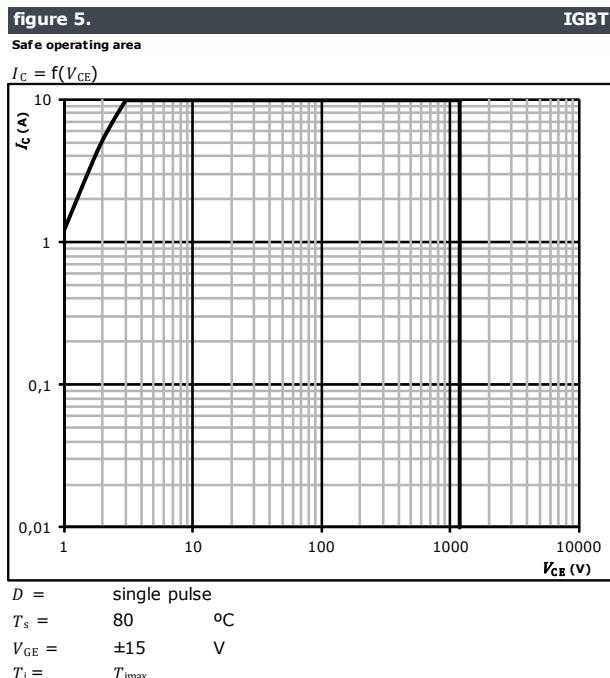




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Inverter Switch Characteristics

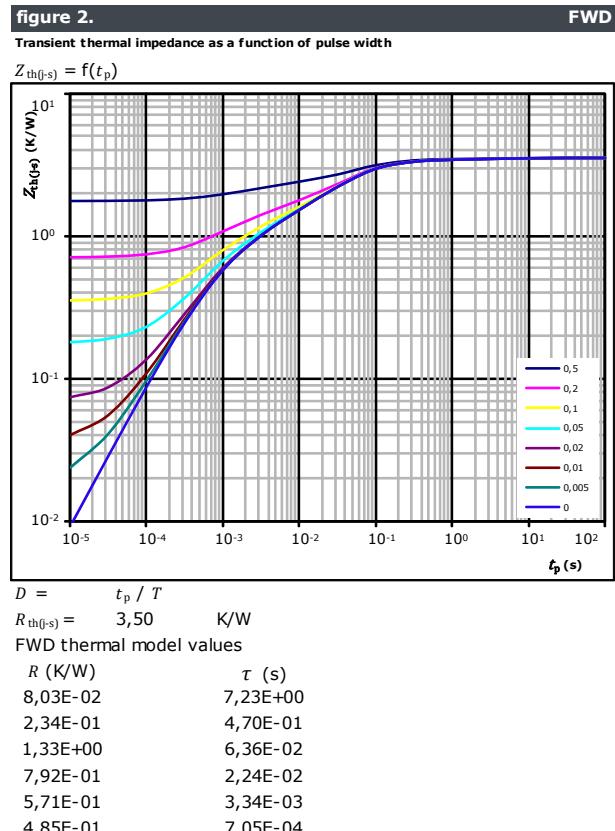
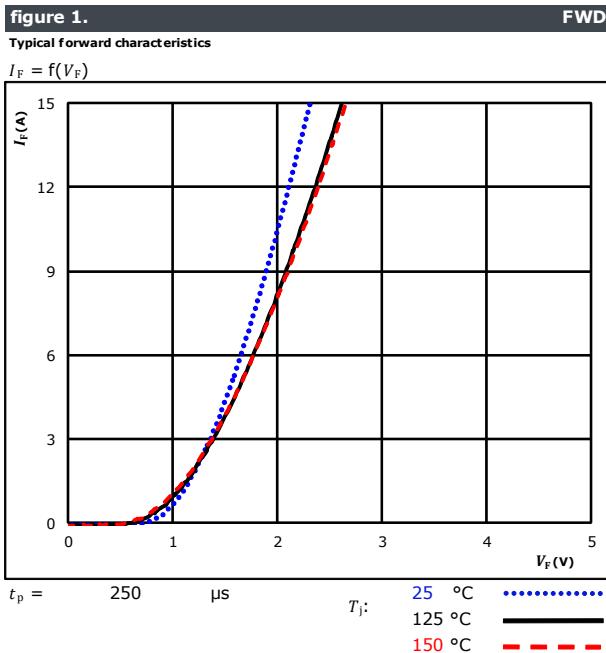




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Inverter Diode Characteristics



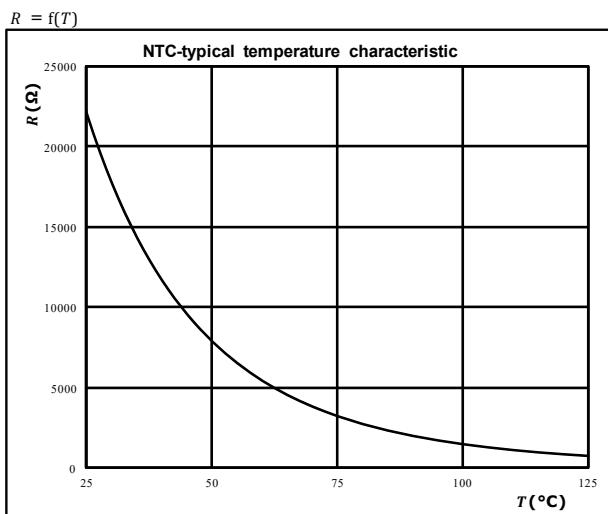


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Thermistor Characteristics

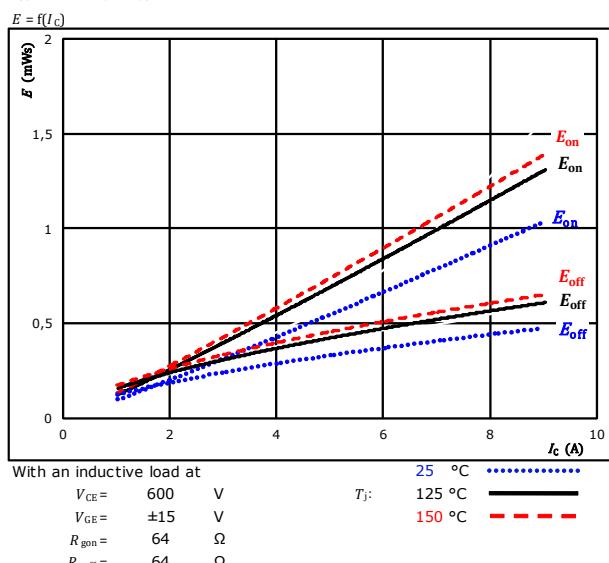
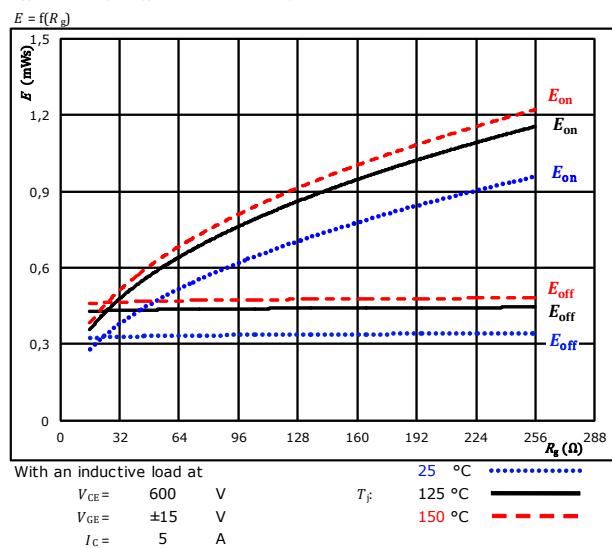
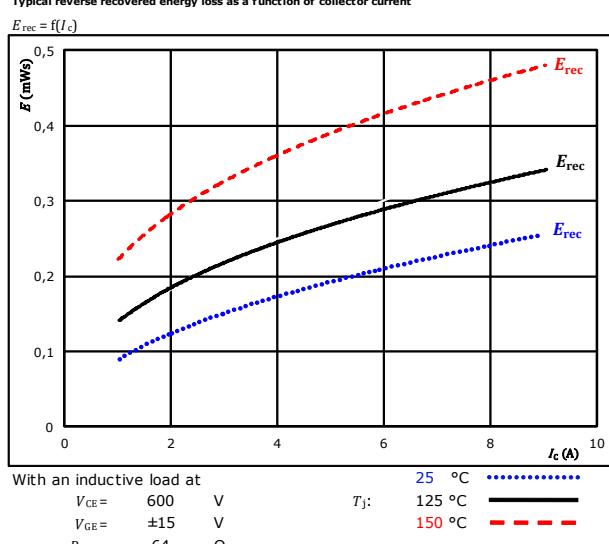
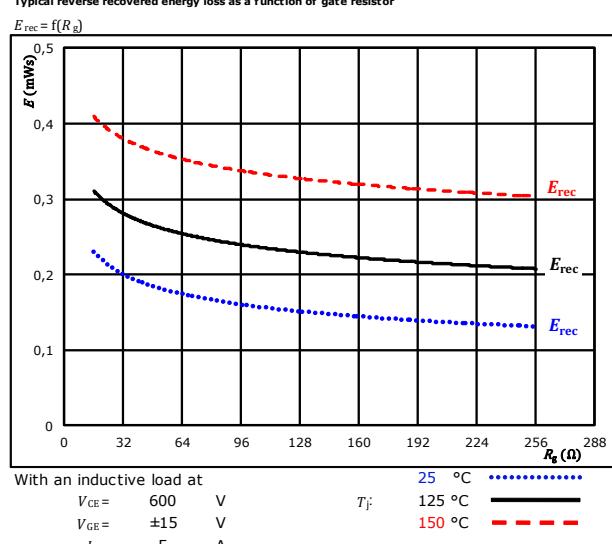
figure 1. Thermistor
Typical NTC characteristic as a function of temperature





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Inverter Switching Characteristics

figure 1.
Typical switching energy losses as a function of collector current**figure 2.**
Typical switching energy losses as a function of gate resistor**figure 3.**
Typical reverse recovered energy loss as a function of collector current**figure 4.**
Typical reverse recovered energy loss as a function of gate resistor



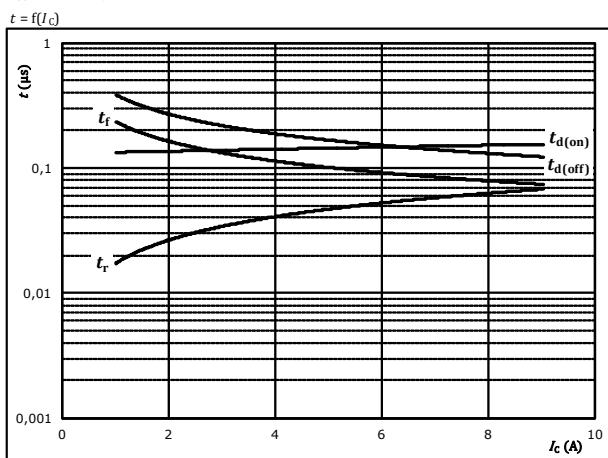
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Inverter Switching Characteristics

figure 5. IGBT

Typical switching times as a function of collector current

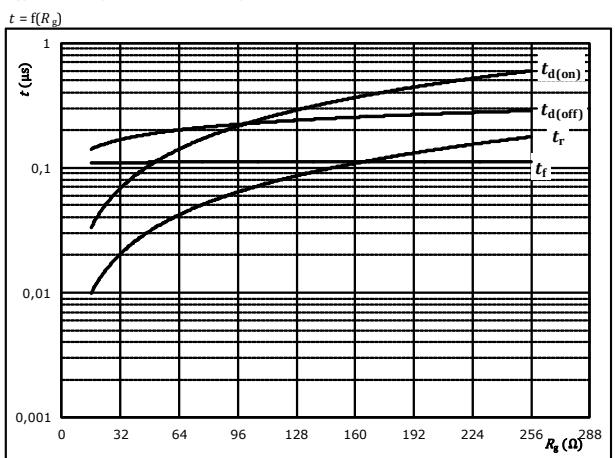


With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$R_{gon} =$	64	Ω
$R_{goff} =$	64	Ω

figure 6. IGBT

Typical switching times as a function of gate resistor

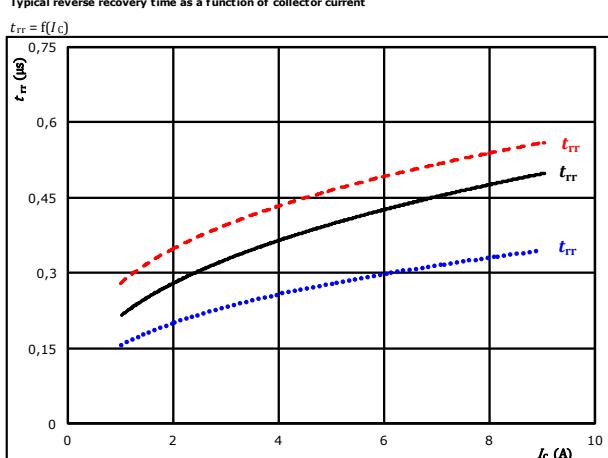


With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$I_c =$	5	A

figure 7. FWD

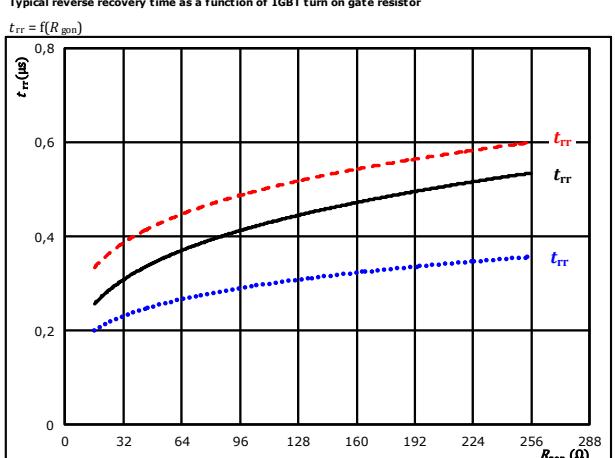
Typical reverse recovery time as a function of collector current



At $V_{CE} = 600$ V $T_j = 25$ °C $\dots\dots\dots$
 $V_{GE} = \pm 15$ V $T_j = 125$ °C $_$
 $R_{gon} = 64$ Ω $T_j = 150$ °C $- - -$

figure 8. FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor

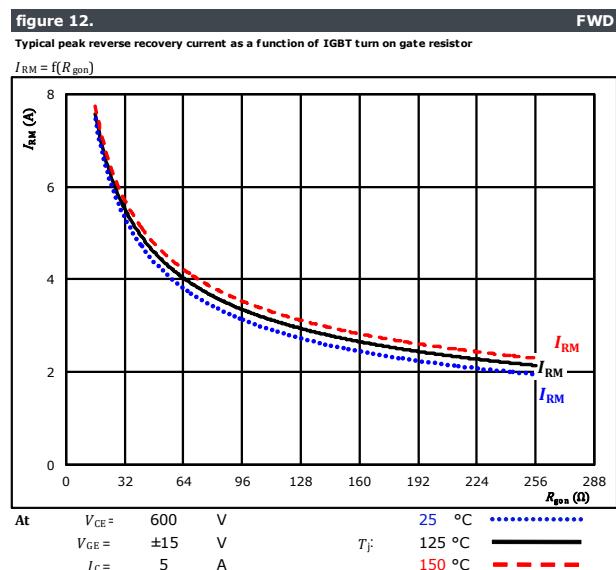
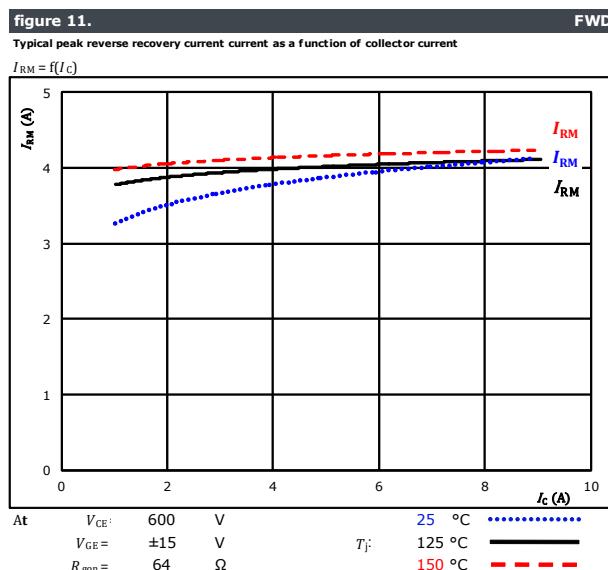
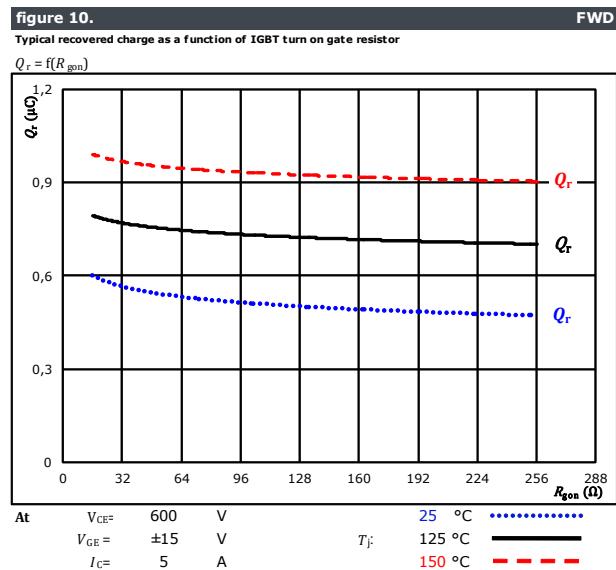
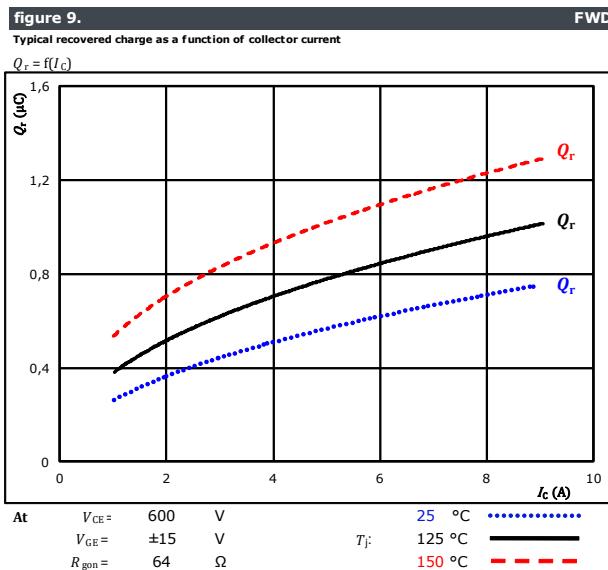


At $V_{CE} = 600$ V $T_j = 25$ °C $\dots\dots\dots$
 $V_{GE} = \pm 15$ V $T_j = 125$ °C $_$
 $I_c = 5$ A $T_j = 150$ °C $- - -$



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Inverter Switching Characteristics

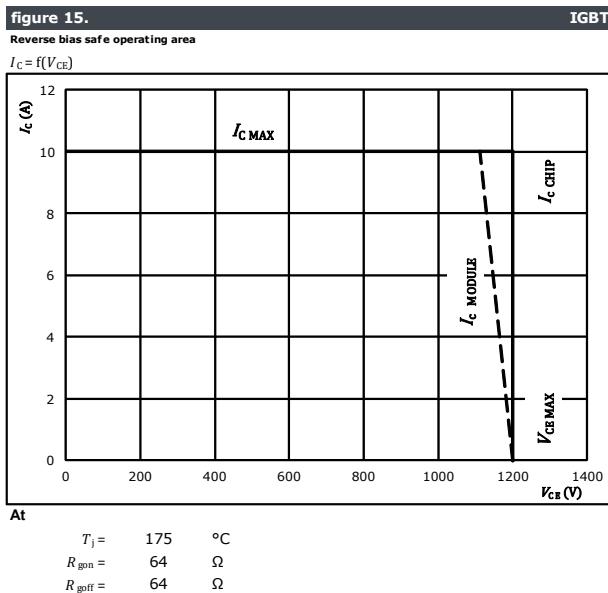
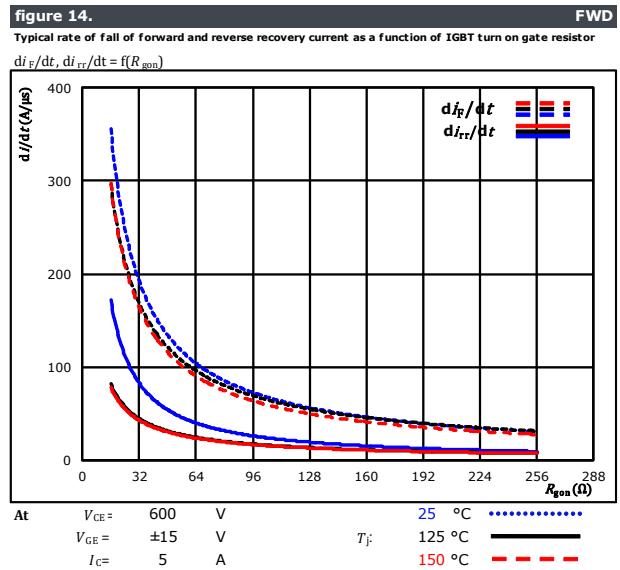
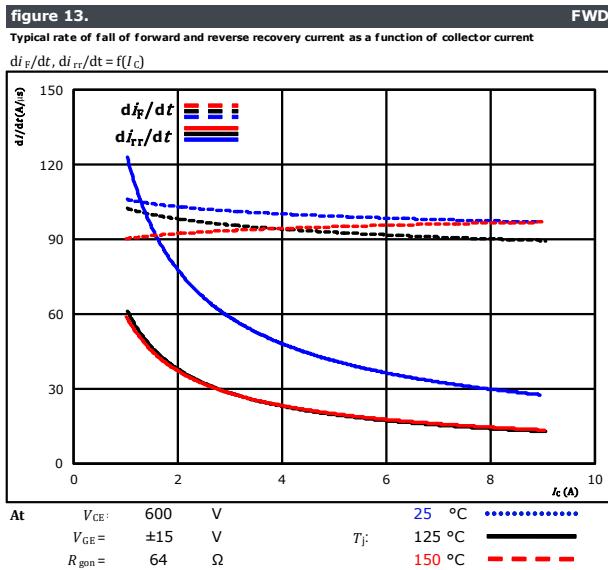




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Inverter Switching Characteristics





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Inverter Switching Definitions

General conditions

T_j	=	125 °C
R_{gon}	=	64 Ω
R_{goff}	=	64 Ω

figure 1.

IGBT

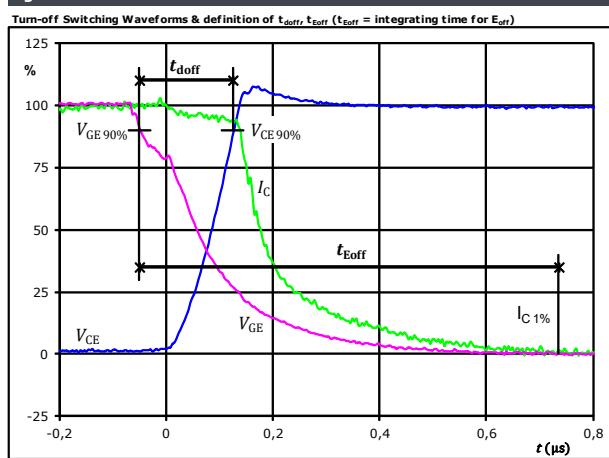


figure 2.

IGBT

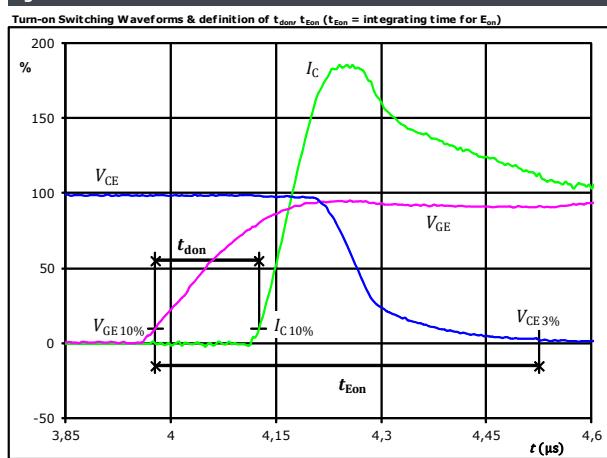


figure 3.

IGBT

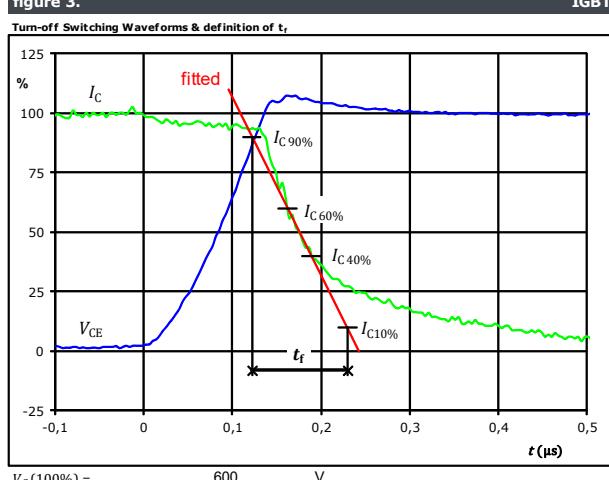
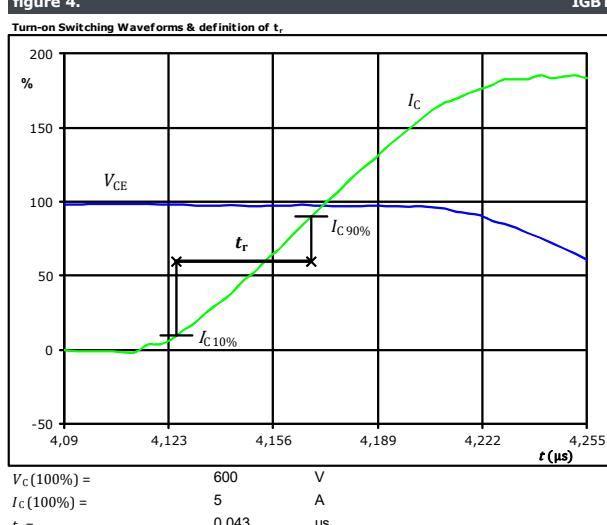


figure 4.

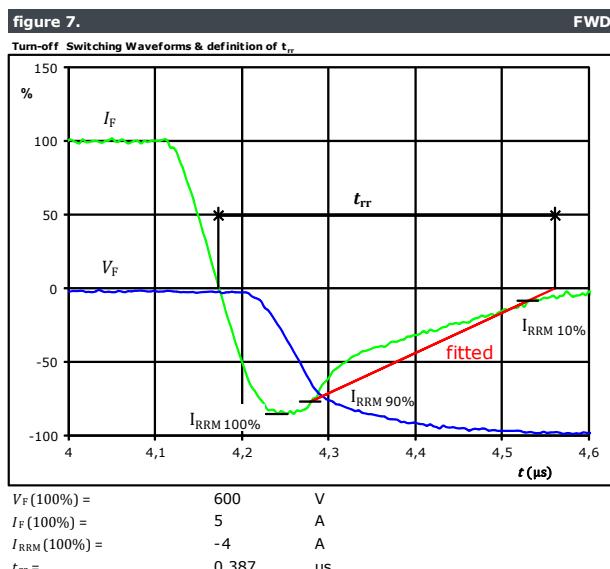
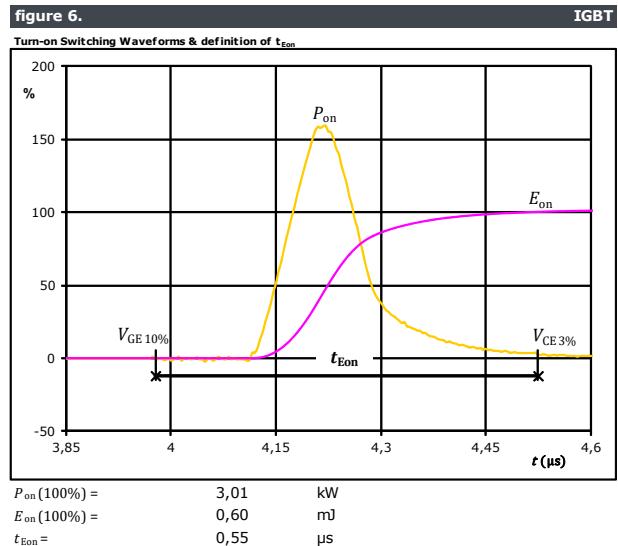
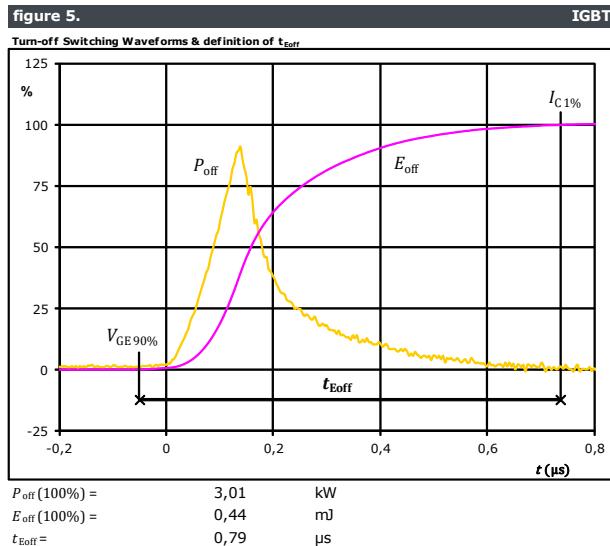
IGBT





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Inverter Switching Characteristics





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Inverter Switching Characteristics

figure 8.

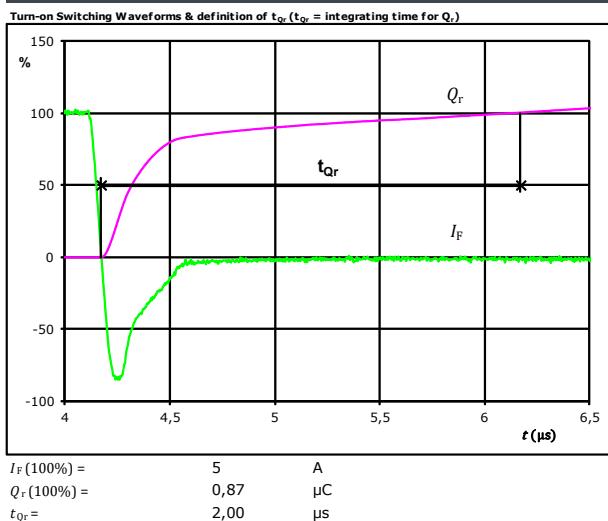
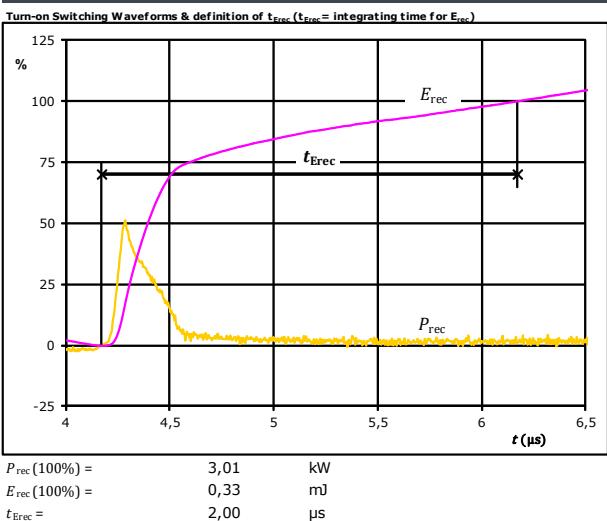


figure 9.





10-F012PNA005M7-P848C29

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Ordering Code & Marking							
Version				Ordering Code			
without thermal paste 12 mm housing with solder pins				10-F012PNA005M7-P848C29			
NN-NNNNNNNNNNNN TTTTTTVV WWYY UL VIN LLLL SSSS							
Text	Name	Date code	UL & VIN	Lot	Serial		
NN-NNNNNNNNNNNN-YYYY	WWYY	UL VIN	LLLLL	SSSS			
Datamatrix	Type&Ver	Lot number	Serial	Date code			
TTTTTTVV	LLLLL	SSSS	WWYY				

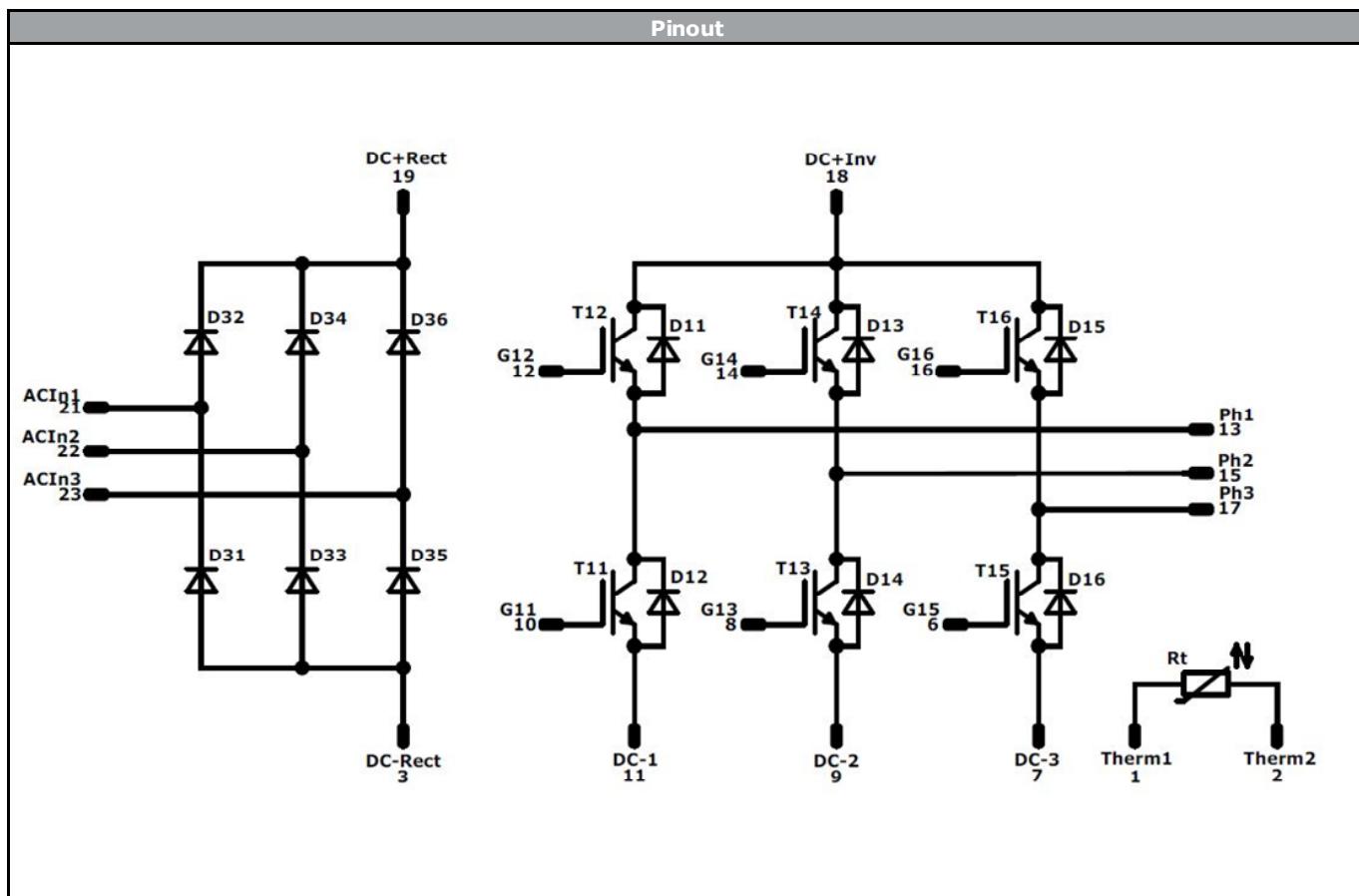
Outline																																																																																																							
Pin table				Outline																																																																																																			
<table border="1"><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>25,5</td><td>2,7</td><td>Therm1</td></tr><tr><td>2</td><td>25,5</td><td>0</td><td>Therm2</td></tr><tr><td>3</td><td>22,8</td><td>0</td><td>DC-Rect</td></tr><tr><td>4</td><td></td><td></td><td>Not assambled</td></tr><tr><td>5</td><td></td><td></td><td>Not assambled</td></tr><tr><td>6</td><td>13,5</td><td>0</td><td>G15</td></tr><tr><td>7</td><td>10,8</td><td>0</td><td>DC-3</td></tr><tr><td>8</td><td>8,1</td><td>0</td><td>G13</td></tr><tr><td>9</td><td>5,4</td><td>0</td><td>DC-2</td></tr><tr><td>10</td><td>2,7</td><td>0</td><td>G11</td></tr><tr><td>11</td><td>0</td><td>0</td><td>DC-1</td></tr><tr><td>12</td><td>0</td><td>19,8</td><td>G12</td></tr><tr><td>13</td><td>0</td><td>22,5</td><td>Ph1</td></tr><tr><td>14</td><td>7,5</td><td>19,8</td><td>G14</td></tr><tr><td>15</td><td>7,5</td><td>22,5</td><td>Ph2</td></tr><tr><td>16</td><td>15</td><td>19,8</td><td>G16</td></tr><tr><td>17</td><td>15</td><td>22,5</td><td>Ph3</td></tr><tr><td>18</td><td>22,8</td><td>22,5</td><td>DC+Inv</td></tr><tr><td>19</td><td>25,5</td><td>22,5</td><td>DC+Rect</td></tr><tr><td>20</td><td></td><td></td><td>Not assambled</td></tr><tr><td>21</td><td>33,5</td><td>15</td><td>ACIn1</td></tr><tr><td>22</td><td>33,5</td><td>7,5</td><td>ACIn2</td></tr><tr><td>23</td><td>33,5</td><td>0</td><td>ACIn3</td></tr></tbody></table>				Pin	X	Y	Function	1	25,5	2,7	Therm1	2	25,5	0	Therm2	3	22,8	0	DC-Rect	4			Not assambled	5			Not assambled	6	13,5	0	G15	7	10,8	0	DC-3	8	8,1	0	G13	9	5,4	0	DC-2	10	2,7	0	G11	11	0	0	DC-1	12	0	19,8	G12	13	0	22,5	Ph1	14	7,5	19,8	G14	15	7,5	22,5	Ph2	16	15	19,8	G16	17	15	22,5	Ph3	18	22,8	22,5	DC+Inv	19	25,5	22,5	DC+Rect	20			Not assambled	21	33,5	15	ACIn1	22	33,5	7,5	ACIn2	23	33,5	0	ACIn3	<p>Outline drawing showing top and side views of the component. Top view dimensions: height 213.405, width 112.5, and a gap of 1 ±0.05 between the top edge and the pins. Side view dimensions: height 213.405, width 16.75, and a gap of 1 ±0.05 at the end of the pins. Pin numbers are indicated by circles: 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11, 12, 13, 14, 15, 16, 17, 18, 19, 20, 21, 22, 23.</p>			
Pin	X	Y	Function																																																																																																				
1	25,5	2,7	Therm1																																																																																																				
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4			Not assambled																																																																																																				
5			Not assambled																																																																																																				
6	13,5	0	G15																																																																																																				
7	10,8	0	DC-3																																																																																																				
8	8,1	0	G13																																																																																																				
9	5,4	0	DC-2																																																																																																				
10	2,7	0	G11																																																																																																				
11	0	0	DC-1																																																																																																				
12	0	19,8	G12																																																																																																				
13	0	22,5	Ph1																																																																																																				
14	7,5	19,8	G14																																																																																																				
15	7,5	22,5	Ph2																																																																																																				
16	15	19,8	G16																																																																																																				
17	15	22,5	Ph3																																																																																																				
18	22,8	22,5	DC+Inv																																																																																																				
19	25,5	22,5	DC+Rect																																																																																																				
20			Not assambled																																																																																																				
21	33,5	15	ACIn1																																																																																																				
22	33,5	7,5	ACIn2																																																																																																				
23	33,5	0	ACIn3																																																																																																				
				<p>Tolerance of pinpositions: ±0.5mm at the end of pins Dimension of coordinate axis is only offset without tolerance</p>																																																																																																			



10-F012PNA005M7-P848C29

datasheet

Vincotech



Identification					
ID	Component	Voltage	Current	Function	Comment
D31, D32, D33, D34, D35, D36	Rectifier	1600 V	25 A	Rectifier Diode	
T11, T12, T13, T14, T15, T16	IGBT	1200 V	5 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1200 V	5 A	Inverter Diode	
Rt	Thermistor	1200 V	5 A	NTC	



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Packaging instruction			
Standard packaging quantity (SPQ) 135	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for flow 0 packages see vincotech.com website.			

Package data			
Package data for flow 0 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-F012PNA005M7-P848C29-D1-14	02 Jul. 2019		

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.